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- (71) Applicant (for all designated States except US): CARL ZEISS SMT AG [DE/DE]; Carl-Zeiss-Strasse 22, 73447 Oberkochen (DE).
- (72) Inventors; and
- (75) Inventors/Applicants (for US only): MANN, Hans-Jürgen [DE/DE]; Katzenbachstrasse 49, 73447 Oberkochen (DE). EPPLE, Alexander [DE/DE]; Langertstrasse 38, 73431 Aalen (DE). HUDYMA, Russell [US/US]; 21 East Ridge Drive, San Ramon, CA 94583 (US).
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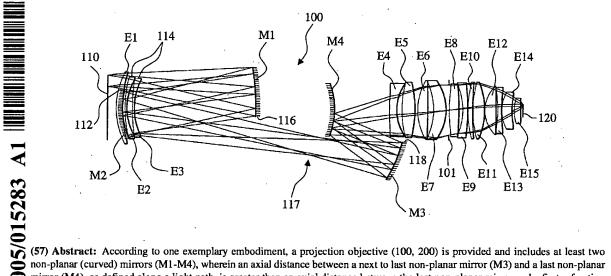
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(54) Title: PROJECTION OBJECTIVES INCLUDING A PLURALITY OF CURVED MIRRORS WITH LENSES AHEAD OF THE LAST BUT ONE MIRROR



(57) Abstract: According to one exemplary embodiment, a projection objective (100, 200) is provided and includes at least two non-planar (curved) mirrors (M1-M4), wherein an axial distance between a next to last non-planar mirror (M3) and a last non-planar mirror (M4), as defined along a light path, is greater than an axial distance between the last non-planar mirror and a first refracting surface of lenses following in the light path. In one exemplary embodiment, the first refracting surface is associated with a single pass type lens. The present objectives form images with numerical apertures of at least about 0.80 or higher, e.g., 0.95. Preferably, the objective does not include folding mirrors and there is no intermediate image between the two mirrors, as well as the pupil of the objective being free of obscuration.



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PROJECTION OBJECTIVES INCLUDING A PLURALITY OF CURVED MIRRORS WITH LENSES AHEAD OF THE LAST BUT ONE MIRROR

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Technical Field

The present invention relates to an optical system, such as projection lithography and more particularly, relates to an optical system with at least two mirrors, preferably at least 4 mirrors, with at least one lens element spatially ahead of mirror M3.

15 Background

In the manufacture of semiconductor devices, photolithography is often used, especially in view of the circuit patterns of semiconductors being increasingly miniaturized in recent years. Projection optics are used to image a mask or reticle onto a wafer and as circuit patterns have become increasingly smaller, there is an increased demand for higher resolving power in exposure apparatuses that print these patterns. To satisfy this demand, the wavelength of the light source must be made shorter and the NA (numerical aperture) of the optical system (i.e., the projection lens) must be made larger.

Optical systems having a refractive group have achieved satisfactory resolutions operating with illumination sources having wavelengths of 248 or 193

nanometers. At these wavelengths, no or only slight correction of chromatic aberration is needed. As the element or feature size of semiconductor devices becomes smaller, the need for optical projection systems capable of providing enhanced resolution increases. In order to decrease the feature size which the optical projection systems used in photolithography can resolve, shorter wavelengths of electromagnetic radiation must be used to project the image of a reticle or mask onto a photosensitive substrate, such as a semiconductor wafer.

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Because very few refractive optical materials are able to transmit significant electromagnetic radiation below a wavelength of 193 nanometers, it is necessary to reduce to a minimum or eliminate refractive elements in optical projection systems operating at wavelengths below 193 nanometers. To date, no second optical material is known which allows for chromatic aberration correction at wavelengths below 160 nm or shorter with sufficient material properties (homogeneity property, availability). Consequently, one has to construct a catadioptric imaging system, such as the present one, in order to allow for correction of chromatic aberrations with the use of only one single material, especially, SiO₂ or CaF₂.

The desire to resolve ever smaller features makes necessary optical projection systems that operate at the extreme ultraviolet wavelengths, below 200 nm; and therefore, as optical lithography extends into shorter wavelengths (e.g., deep ultraviolet (DUV) or very ultraviolet (VUV)), the requirements of the projection system become more difficult to satisfy. For example, at a wavelength of 157 nm, access to 65 nm design rules requires a projection system with a numerical aperture of

at least 0.80. As optical lithography is extended to 157 nm, issues relating to resist, sources and more importantly calcium fluoride have caused substantial delays to the development of lithography tools that can perform satisfactorily at such wavelengths.

In response to the technical issues relating to the source and the material, it is important that projection system development investigates and focuses on maximizing spectral bandwidth to an order of 1 pm, while simultaneously minimizing the deficiencies associated with the materials that are used, i.e., it is desirable to minimize the calcium fluoride blank mass.

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It has long been realized that catadioptric reduction optical systems (i.e., ones that combine a reflective system with a refractive system) have several advantages, especially in a step and scan configuration, and that catadioptric systems are particularly well-suited to satisfy the aforementioned objectives. A number of parties have developed or proposed development of systems for wavelengths below 365 nm. One catadioptric system concept relates to a Dyson-type arrangement used in conjunction with a beam splitter to provide ray clearance and unfold the path to provide for parallel scanning (e.g., U.S. patent Nos. 5,537,260; 5,742,436; and 5,805,357). However, these systems have a serious drawback since the size of the beam-splitting element becomes quite large as the numerical aperture is increased, thereby making the procurement of optical material with sufficient quality (in three dimensions) to make the cube beam splitter a high risk endeavor, especially at a wavelength of 157 nm.

The difficulties associated with the cube beam splitter size are better managed by locating the cube beam splitter in the short conjugate of the system,

preferably near the reticle or at its 1x conjugate if the design permits. Without too much effort, this beam splitter location shrinks the linear dimension of the cube by up to 50%, depending upon several factors. The advantages of this type of beam splitter placement are described in U.S. patent No. 5,052,763 to Wilczynski. Further, U.S. patent No. 5,808,805 to Takahashi provides some different embodiments; however, the basic concept is the same as in Wilczynski.

It is also possible to remove the cube beam splitter entirely from the catadioptric system. In one approach, an off-axis design is provided using a group with a numerical aperture of 0.70 operating at 248 nm. In U.S. patent Nos. 6,195,213 and 6,362,926 to Omura et al. disclose other examples of this approach and U.S. patent No. 5,835,275 to Takahashi illustrates yet another example. Takahashi et al. offer several similar examples of beam splitter free designs in European patent application EP 1168028.

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Most of these "cubeless" embodiments share a common theme, namely that the catadioptric group contains only a single mirror. Additional mirrors can possible be used to improve performance. However, pure reflective designs with multiple mirrors have been investigated but have largely failed because these designs have proven unable to achieve adequately high numerical apertures (e.g., U.S. patent Nos. 4,685,777; 5,323,263; 5,515,207; and 5,815,310).

Another proposed solution is disclosed in U.S. patent No. 4,469,414 in which a restrictive off-axis field optical system is disclosed. The system disclosed in this reference does not include a doubly passed negative lens in a first partial objective. Further, the embodiments disclosed therein are of impractical geometry

and of far too low numerical aperture to provide improved lithography performance in the ultraviolet wavelength region.

In conventional practice, four mirror catadioptric configurations typically are limited in terms of their numerical apertures due to the location of the refractive lens part relative to the mirrors of the system.

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U.S. patent application publication No. 2002/0024741 discloses various projection optical systems including one in which a lens element is positioned spatially in front of mirror M3; however, in this embodiment, the lens element that is positioned in front of mirror M3 is a double pass type lens element. The use of a double pass lens element complicates the system design because the use of a double pass lens between mirrors M3 and M4 requires the double pass lens to be close to mirror M4 and therefore it is difficult to mount.

In addition, there are a number of other differences between the system disclosed in this published application and the present system. For example, Fig. 26 of the 2002/0024741 publication discloses a single pass lens element optically disposed between the very first mirror and the very last mirror of the whole system. Unfortunately, this element is very large in diameter and therefore difficult to manufacture. The disadvantage of such a single pass lens element is that it either requires a lateral separation of beam bundles traveling between the various mirrors, resulting in a large diameter of the lens or that it has to be physically disposed between the backside of mirror #1 and the backside of mirror #4 as shown in each of the figures 23 to 28, again leading to a large diameter of the lens. As will be described in greater detail hereinafter, the present embodiments do not suffer from

this disadvantage since the present lens elements are not required to be very large in diameter. With respect to the location of the aperture stop, the embodiments in the publication (as shown in Figs. 20-28) have an aperture stop located in front of the refractive group Gr2 with the aperture stop separating it from the field mirror group Grf.

U.S. patent No. 5,323,263 to Schoenmakers discloses an embodiment in which there are multiple mirrors used in which a number of lens elements are disposed between the most optically forward mirror and the second most optically forward mirror. The lens elements between these two mirrors are all single mirrors.

What has heretofore not been available is a catadioptric projection system, especially a four mirror design, that has particular utility in 157 nm lithography and produces an image with a numerical aperture of at least 0.80 and includes other desirable performance characteristics.

15 Summary

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Various photolithographic reduction projection objectives according to a number of embodiments are provided herein. An exemplary projection objective includes at least two non-planar mirrors, wherein an axial distance between a next to last non-planar mirror and a last non-planar mirror, as defined along a light path (optical axis), is greater than an axial distance between the last non-planar mirror and a first refracting surface of lenses following in the light path. In one embodiment, the first refracting surface is associated with a single pass type lens. The present

objectives form images with numerical aperture of at least about 0.80 or higher, e.g., 0.95.

In one aspect of the present invention, each of the present objectives consists of two parts, namely a catadioptric and a refractive part. According to the present designs, each of the refractive lens parts is advanced towards the front and thus begins already in front of the third mirror M3. This is in contrast to conventional designs that include at least four mirrors and by moving the refractive part forward, high numerical aperture is achieved in a four mirror configuration. Moreover, the present system is configured so that a pupil thereof is free of obscuration, thereby resulting in an improved image.

An exemplary objective includes one more of the following features:

(1) at least one of four aspherical lens surfaces and four aspherical mirror surfaces;

(2) at least four non-planar mirrors; and (3) includes at least one light-dispersing mirror and at least two light-collecting mirrors. In addition, the objective does not have folding mirrors and also does not have an intermediate image between the two mirrors and in at least one embodiment, there is only one lens element (single pass type) between the next to last and last mirrors.

Other features and advantages of the present invention will be apparent from the following detailed description when read in conjunction with the accompanying drawings.

Brief Description of the Drawing Figures

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The foregoing and other features of the present invention will be more readily apparent from the following detailed description and drawings figures of illustrative embodiments of the invention in which:

Fig. 1 schematically illustrates a microlithographic projection reduction objective according to a first embodiment; and

Fig. 2 schematically illustrates a microlithographic projection reduction objective according to a second embodiment.

Detailed Description of Preferred Embodiments

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In order to provide the above advantages and to solve problems discussed above with respect to the related art systems, catadioptric projection systems according to a number of different embodiments are provided. The present systems achieve numerical apertures up to and in excess of 0.80 while overcoming the disadvantages associated with the prior art.

Referring first to Fig. 1, a catadioptric multi-mirror projection reduction objective 100 according to a first embodiment is illustrated. Fig. 1 is a schematic optical diagram of the system 100 illustrating the system 100 in an manner to generally show the arrangement of the elements. The system 100 includes a plurality of mirrors and a plurality of lens elements that are arranged in distinct groups and in predetermined locations relative to the mirrors.

For purpose of the present application, the term "optically in front of" refers to a situation where light rays impinge upon a first element prior to a second element, thus making the first element optically in front of the second element. The

example, the second element is optically behind the first element since the light rays first encounter the first element. The terms "physically in front of" or "spatially in front of" and "physically behind" or "spatially behind" define spatial relationships between the surface vertexes of two elements irrespective of the path of the light rays and only with reference to a point of reference.

In the illustrated embodiment, the system 100 includes a reticle (object) 110 and contains more positive lens elements than negative lens elements and more specifically and as detailed below, one exemplary system 100 includes 15 lens elements with 10 being positive lens elements and 5 being negative lens elements.

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The system 100 includes the reticle 110 and a wafer 120 on which a reduced image is formed based on the reticle 110 as is commonly known. Beginning from the least image forward element and ending with the most image forward element along the optical path of the system 100, the system 100 includes a first lens element E1 that is disposed between the reticle 110 and a mirror M2. The first lens element E1 is a positive lens through which the light rays pass from one or more points of the reticle 110 toward the mirror M2. The mirror M2 is preferably a curved mirror (e.g., spherical or aspherical mirror) and in the illustrated embodiment, the mirror M2 does not include a continuous reflective surface but rather the mirror M2 has one or more regions where an opening 112 or the like is formed to permit free passage of light rays therethrough without being influenced at all by the mirror M2. The one or more openings 112 are formed in the mirror M2 at locations that are optically aligned with locations where the light rays pass through the first lens

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element E1. Alternatively, it will be appreciated that the mirror M2 can be constructed and arranged as an off axis mirror so that the mirror M2 is positioned off axis at locations that permit the light rays to pass by the mirror M2.

Optically and physically behind the mirror M2 is a pair of second and third lens elements E2 and E3, respectively. Each of the lens elements E2 and E3 is a negative lens and because of the arrangement between mirror M2 and mirror M1 and the physical construction of the lens elements E2 and E3, the lens elements E2 and E3 act as double pass lenses. More specifically, the lens elements E2 and E3 are disposed between mirror M2 and mirror M1 and similar to the mirror M2, the lens elements E2 and E3 do not have an entirely continues surface but rather one or more openings 114 are formed in each lens element to permit light rays to freely pass therethrough without being influenced by the lens elements. The one or more openings 114 are optically aligned with the one or more openings 112 formed in the mirror M2 so that the light rays that pass through the openings or cut outs 112 in the mirror M2 before then passing through the opening or cut outs 114 in the lens elements E2 and E3 before contacting the reflective surface of mirror M1. Once again and instead of having a physical opening formed therein, the lens elements E2 and E3 can be constructed so that they are formed and arranged so that the light rays passing by the mirror M2 also pass by and not through the lens elements E2 and E3. The mirror M1 is preferably a curved mirror (e.g., spherical or aspherical mirror). One will appreciate that the mirrors M1 and M2 are both light collecting mirrors.

It will be appreciated that mirror M1 is the first mirror in the optical path since the light rays initially pass through openings 112 formed in mirror M2 and

only later strike the reflective surface of mirror M2 after having contacted and been reflected by the surface of mirror M1. After being reflected by the mirror M1, the light rays are directed toward the mirror M2 and first pass through lens element E2 and E3 before striking the reflective surface of mirror M2. As previously mentioned, the lens elements E2 and E3 are double pass types lenses since the light rays travel first through the lens elements as they travel from mirror M1 to mirror M2 and then pass through the lens elements a second time as the light rays are reflected by mirror M2 toward a mirror M3 which is preferably a curved mirror (e.g., spherical or aspherical mirror). Mirror M3 is a light collecting mirror.

Mirror M1 is also constructed so that it includes one or more openings or cut outs 116 to permit passage of the light rays from mirror M2 to a reflective surface of mirror M3. As will be appreciated by the illustration of Fig. 1, the mirror M1 has one or more active regions that reflect light rays as well as containing the one or more openings or cut outs 116 to permit the lights rays to travel along the optical path of the system 100, e.g., from mirror M2 to mirror M3, which are both optically behind mirror M1. Again, mirror M1 can be constructed as an off axis mirror that permits the light rays to pass thereby from the mirror M2 to the mirror M3.

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A mirror M4 is positioned physically in front of but optically behind the mirror M3 such that a reflective surface of mirror M3 faces a reflective surface of mirror M4. Mirror M4 is preferably a curved mirror (e.g., spherical or aspherical mirror). As will be described in greater detail hereinafter, mirror M3 includes an opening or cut out 118 formed therein to accommodate a lens element. Mirror M4 is a light dispersing mirror. Mirror M3 can similarly be formed as an off axis mirror

that is constructed and designed to permit the light rays to pass thereby after the light rays are reflected by the mirror M4.

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According to one aspect of the present invention, a lens element, namely a fourth lens element E4, is disposed between the mirror M3 and mirror M4 such that the lens element E4 is physically in front of mirror M3 but optically behind both mirrors M3 and M4. The lens element E4 is a negative lens that is positioned proximate the mirror M3 and as will be appreciated by viewing Fig. 1, the lens element E4 acts as a single pass lens element in that the light rays only pass through the lens element E4 once as they travel according to the optical path of the system 100. This is a difference between other lens designs where a lens element that may be placed between mirror M3 and M4 is positioned close to mirror M4 such that the lens element acts as a double pass lens element since the light rays pass once therethrough to the reflective surface of M4 before then passing through the lens element a second time as the light rays travel in a direction toward M3.

The system 100 includes a fifth lens element E5 that is disposed within the opening or cut out 118 formed in the mirror M3. The lens elements E4 and E5 are disposed along the optical axis so that light rays that are reflected from mirror M4 pass through the lens element E4 and then through lens element E5 which is contained within the mirror M3. In other words, the mirrors M3 and M4 are both optically in front of the lens elements E4 and E5. In the illustrated embodiment, the lens element E5 is a positive lens element that at least partially extends beyond one face of the mirror M3 as well as an opposite face of the mirror M3.

The system 100 is designed so that there are a group of lens elements that are both physically and optically behind the mirror M3 and the lens elements E4 and E5. According to one exemplary embodiment, there are ten lens elements that are disposed optically behind the lens element E5 and more specifically, lens elements E6 to E15 are disposed along the optical axis and optically behind the lens element E5 and optically and physically in front of the wafer 120. Lens elements E6-E8 are positive lenses, lens element E9 is a negative lens, lens elements E10-E12 are positive lenses, lens element E13 is a negative lens; and lens elements E14 and E15 are positive lenses.

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As will be appreciated with reference to Fig. 1, an intermediate image is produced in the light path at the axial location of M4. In order to ensure that no vignetting occurs, the light path has to be routed so that it completely by-passes mirror M4 and it has to be ensured that the light rays do not fall into the central opening (bore) 118 of mirror M3. This requires large deflection angles and thus large refractive powers (or reciprocal of the focal length) in the mirrors M3 and M4 as well as high incidence angles, especially on mirror M4.

The large ray angles after M4 have the effect that the main rays converge rapidly towards the optical axis. Thus, the diaphragm position is pulled closer to mirror M4. However, in order to be able to effectively correct chromatic variation of the magnification, it is necessary to use refractive power in front of the aperture diaphragm. This is possible only by pulling the lenses of the refractive portion spatially (physically) ahead of M3.

This (the need for pulling the lenses of the refractive portion spatially ahead) is considered a direct consequence of the high aperture of this design arrangement. In other words, the arrangement of the lens elements and mirrors as illustrated in Fig. 1 permit it possible to achieve high numerical aperture values in designs of this kind. For example, the system 100 has a numerical aperture of at least about 0.80.

In addition, the present system 100 has a conjugate aperture stop between mirrors M1 and M2, while the aperture stop is located in a back part of the lens arrangement which acts as the refractive part. More specifically, the aperture stop is indicated by marker 101 in Fig. 1 (which is a position immediately spatially and optically in front of lens element E8).

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One of the advantages of the present system 100 is that there is no obscuration of the pupil. In other words, there is no central obscuration in the present system and therefore, all of the disadvantages associated with having a central obscuration are eliminated in the present design. As a result of the present lens system being free of a central obscuration of the pupil, the performance of the system is not jeopardized and the quality of the image is similarly not jeopardized or reduced since the presence of a central obscuration will prevent all of the light rays from passing through to form the image.

A complete optical description is found in Table 1, describing the optical surfaces of the system 100.

Now referring to Fig. 2 in which a catadioptric multi-mirror projection reduction objective 200 according to a second embodiment is illustrated. Fig. 2 is a

schematic optical diagram of the system 200 illustrating the system 200 in an manner to generally show the arrangement of the elements. The system 200 includes a plurality of mirrors and a plurality of lens elements that are arranged in distinct groups and in predetermined locations relative to the mirrors.

In the illustrated embodiment, the system 200 includes a reticle 210 and contains more positive lens elements than negative lens elements and more specifically and as detailed below, one exemplary system 200 includes 20 lens elements with 13 being positive lens elements and 7 being negative lens elements.

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The system 200 includes the reticle 210 and a wafer 220 on which a reduced image is formed based on the reticle 210 as is commonly known. Beginning from the least image forward element and ending with the most image forward element along the optical path of the system 200, the system 200 includes a first lens element E1 and a second lens element E2 that are disposed between the reticle 210 and a mirror M2. The first and second lens elements E1 and E2 are positive lenses through which the light rays pass from one or more points of the reticle 210 toward the mirror M2. The mirror M2 is preferably a curved mirror (e.g., spherical or aspherical mirror) and in the illustrated embodiment, the mirror M2 does not include a continuous reflective surface but rather the mirror M2 has one or more regions where an opening 212 or cut out or the like is formed to permit free passage of light rays therethrough without being influenced at all by the mirror M2. The one or more openings 212 are formed in the mirror M2 at locations that are optically aligned with locations where the light rays pass through the E1 and E2 and then through the mirror M2.

As previously mentioned, mirror M2 does not necessarily have to have a physical opening formed therethrough but instead it can be constructed as an off axis mirror that is positioned so that the light rays travel thereby from lens elements E1 and E2 to lens element E3.

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The system 200 includes a third lens element E3 that is disposed physically (spatially) and optically behind the mirror M2. The light rays traveling through openings 212 formed in the mirror M2 subsequently travel through the lens element E3. In the illustrated embodiment, the third lens element E3 is a negative lens and is characterized as a triple pass lens element since the lights rays pass through this lens element three distinct times as the light rays travel along the optical path of the system 200.

The system 200 includes fourth and fifth lens elements E4 and E5 that are spatially and optically behind the lens element E3. In the illustrated embodiment, the lens elements E4 and E5 are negative lenses. The lens elements E4 and E5 are disposed spatially proximate to the mirror M1 such that light rays that pass through the lens element E3 pass through the lens elements E4 and E5 before contacting the reflective surface of the mirror M1. It will be appreciated that the lens elements E4 and E5 are double pass type lens elements since the lights rays pass through this lens element two distinct times as the light rays travel along the optical path of the system 200. More specifically, after the light rays contact the mirror M1, the light rays pass back through the lens elements E4 and E5 as the rays travel toward the mirror M2. Before the light rays contact the mirror M2, the light rays pass through the lens element E3 for a second time and then after the light rays contact the mirror M2, the

light rays are reflected back through the lens element E3 for a third time (resulting in E3 being a triple pass lens). Preferably, the openings 212 of mirror M2 are formed in one region while the mirror M2 has another region that acts as a reflective mirror surface for reflecting the light rays from mirror M1. Mirror M1 is a light collecting mirror, while mirror M2 is a light dispersing mirror. Alternatively, the mirror M2 can be an off axis mirror without a physical opening 212 formed therethrough.

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After the light rays pass through the lens element E3 for a third time, the light rays are directed to a mirror M3. The mirror M3, like mirrors M1 and M2, is a curved mirror (e.g., spherical or aspherical mirror). In the illustrated embodiment, the mirror M3 is centered off of the optical axis so that it includes an off axis region, generally indicated at 220, that receives the light rays from the mirror M2 as shown in Fig. 2. In other words, the mirror M3 is coaxially aligned but only used at an off-axis region.

The system 200 includes a mirror M4 that is spatially in front of but

optically behind the mirror M3. As shown, the mirrors M1 and M4 are positioned
back-to-back relative to one another with no lens elements being disposed
therebetween. Mirror M3 is a light collecting mirror, while mirror M4 is a light
dispersing mirror.

According to one aspect of the present invention and similar to the above described first embodiment, a lens element, namely a sixth lens element E6, is disposed between the mirror M3 and mirror M4 such that the lens element E6 is physically in front of mirror M3 but optically behind both mirrors M3 and M4. The lens element E6 is a positive lens that is positioned proximate the mirror M3 and as

will be appreciated by viewing Fig. 2, the lens element E6 acts as a single pass lens element in that the light rays only pass through the lens element E6 once as they travel according to the optical path of the system 200 in contrast to other lens designs (e.g., see U.S. Patent Application publication No. 2002/0024741) in which the lens element acts as a double pass lens element.

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The lens element E6 is positioned next to the mirror M3 in a region where the mirror M3 has one or more openings or cut outs 214 formed therethrough to permit the light rays that travel through the lens element E6 to then subsequently pass through the one or more openings 214 as the light travels according to the light path of the system 200. In other words, the lens element E6 preferably extends at least partially through the opening 214. Again, mirror M3 can be an off axis mirror that is positioned to permit the light rays to travel along the optical path from mirror M4.

The system 200 is designed so that there are a group of lens elements that are both physically and optically behind the mirror M3 and the lens elements E6. According to one exemplary embodiment, there are fourteen lens elements that are disposed optically behind the lens element E6 and more specifically, lens elements E7 to E20 are disposed along the optical axis and optically behind the lens element E6 and optically and physically in front of the wafer 120. Lens element E7 is a negative lens, lens elements E8 and E9 are positive lenses, lens element E10 is a negative lens, lens element E11 is a positive lens, lens element E12 is a negative lens, lens elements E13-E16 are positive lenses, lens element E17 is a negative lens, lens elements E18-E20 are positive lenses.

In other words, the arrangement of the lens elements and mirrors as illustrated in Fig. 2 permit it possible to achieve high numerical aperture values in designs of this kind. For example, the system 200 has a numerical aperture of at least about 0.95. A conjugate aperture stop is located between the reticle 210 and the mirror M1, while the aperture stop is located in a back part of the lens arrangement which acts as a refractive part. More specifically, the aperture stop in system 200 is indicated by marker 201 in Fig. 2.

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As with the system 100, the system 200 is advantageously free of obscuration of the pupil (e.g., central obscuration) and therefore, the quality of the image is not jeopardized.

A complete optical description is found in Table 2, describing the optical surfaces of the system 200.

While, the term "opening", "bore" and "cut out" has been used throughout the present specification, one will appreciate that the lenses can be constructed in a number of other different ways to accomplish the same objective which is to permit the free passage of lights rays therethrough. Thus, these terms are only exemplary and not limiting of the present design. In addition, the shape of the opening or cut out can be varied and is not limited to any particular shape or size so long as the openings and cut outs perform the intended function. In addition, the mirror and refractive lens elements can be constructed so that they do not include a physical opening formed therethrough but rather the mirror or lens element is constructed as an off axis element to permit the light rays to travel along the optical path without any interference by this element.

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In one aspect of the present invention, each of the present objectives has a refractive lens part that is advanced towards the front and thus begins already in front of the third mirror M3. This is in contrast to conventional designs that include at least four mirrors and by moving the refractive part forward, high numerical aperture is achieved in a four mirror configuration.

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Moreover, it is understood that the present systems disclosed herein are not limited to "dry systems" with numerical apertures less than 1.0 but rather the present designs can also be implemented in "immersion systems" with numerical apertures greater than or equal to 1.0. Thus, implementation of the present systems in immersion lithography is within the teachings of the present application.

While U.S. patent No. 5,323,263 discloses an arrangement in which there are multiple mirrors between the most optically forward mirror and the second most optically forward mirror; however, there are a number of differences between this system and the present embodiments. More specifically, in at least one of the present embodiments, there is only a single lens element of a single pass type that is disposed between mirror M3 and mirror M4. Moreover and in direct contrast to the arrangements in the '263 patent, the present embodiment does not include folding mirrors. Also, the present embodiments do not have an intermediate image between the two mirrors.

As previously mentioned, there are a number of differences between the present embodiments and those disclosed in U.S. patent application publication No. 2002/0024741. In the present embodiments, there is no single pass mirror between mirrors should be M1 and M4 and therefore, the present embodiments do not

have the constraints of having to have a very large diameter lens element in contrast to the 2002/0024741 publication. This makes the present system easier to manufacture.

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According to one exemplary embodiment, there is a limit of the maximum diameter of the lens elements with respect to the diameter of the aperture stop. For example, in the second embodiment disclosed herein, the maximum diameter of each lens element is less than 1.1 times the diameter of the aperture stop, whereas in the embodiments shown in Figs. 23-28 of the 2002/0024741 publication, the quotient between the two diameters is at least 1.5, which means that there is again a huge lens element which leads to manufacturing problems. Even in the embodiments disclosed in Figs. 20 and 22, the quotient is greater than 1.1.

Moreover, the location of the aperture stop in the present embodiments is different from the location in the 2002/0024741 publication and this leads to advantages. As shown in Figs. 20-28 of the 2002/0024741 publication, the aperture stop is located in front of the refractive group Gr2 and separates it from the field mirror group Grf. In the present embodiments, the aperture stop is disposed in the rear part of the refractive group. This means that there is at least one lens element of the refractive group in front of the aperture stop. The advantage of such a position of the aperture stop is the fact that it allows for correction of the chromatic variation of magnification (also known as "later color").

The present embodiments thus include at least two curved (non-planar) mirrors as well as a plurality of optical elements that have a common axis of rotational symmetry. It will be appreciated that while rotational symmetry is a

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property of the mathematical surface of the optical element, Applicants are using this term to describe whether the optical element is on or off a common axis. Thus, the term describes whether the optical element is off-axis or not. The axial distance between two elements, such as a mirror and a lens element or two mirrors is defined as the distance between the vertices of the surfaces. In the present system, the off axis mirrors have only virtual vertices and therefore, when computing the axial distance between the off axis mirror and another element, this is taken into account. In addition, when an optical element is discussed as being physically between the first and second mirrors it refers to an optical element that is between the physically existing off-axis mirrors.

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While exemplary drawings and specific embodiments of the present invention have been described and illustrated, it is to be understood that the scope of the present invention is not to be limited to the particular embodiments discussed. Thus, the embodiments shall be regarded as illustrative rather than restrictive, and it should be understood that variations may be made in those embodiments by workers skilled in the art without departing from the scope of the present invention as set forth in the claims that follow, and equivalents thereof. In addition, the features of the different claims set forth below may be combined in various ways in further accordance with the present invention.

Table 1

				•		
	•					
j890		•			. •	
•	•	•		BRECHZAHL	1/2 PREIER	
FLAE	CHE RADIEN	DICKEN	Glaeser	157.63 nm	DURCHMESSER	
0	0.00000000					
1	0,0000000000 192,995627126As	18.000000000 12.518798156	03.00 min	1.00000000	72.500	
2	291.389631363	274.544091677	CAFL_VUV	1.55928800	77.985	
3	-649,856314294AS	-250.533863230		1.00000000	77.583 92,471	REFL
. 4	146.689104606	-3,750000000	CAPI_VUV	1.55928800	57.639	Kern
5	540.274698809	-11.201018265		1.0000000	61.361	
6	134.962915715	3.750000000	CAFL_VUV	1,55928800	61.340	
7	300.894447330	-9.309210182	_	1.00000000	66.413	
g. 9	173.97231255BAS	,	•	1,000000000	66.174	REFL
10	300.894447330 134.9629 1 5715	3.750000000	CAFL_VUV	1.55928800	66.275	
11 .	540.274698809	11.201018265 3.750000000	C3 550 :	1.00000000	63.401	
12	146.689104606	558.441270617	CYLT ALA	1.55928800	63.472	
13	-317.532326155AS	-146.217379134		1.00000000 1.00000000	62.164 152.413	
14	-193.169921455AS	111.338004385	•	1.00000000	57.345	refl Refl
15	544.351140924 A 5	15.000000000	CAFL_VUV	1.55928800	56.680	WDt D
. 16	112.257898711	10.395792988	-	1.00000000	56.810	•
17	264.833194633	25.883573664	CYAFT ANA	1.55928800	57,316	
18	-293,961910609	5.417147144		1.00000000	59.447	
19	137,486688475	20.953421004	CAFL_VÚV	1.55928800	62.932	
20 21	-3025.153068.070	11.399646108		1.00000000	52,414	
22	-167,500442889 -124.000000000	25.171253731	CYLT_AGA	1.55928800	62.418	
23	. 0.000000000	5.678103829 '0.50000000	•	1.00000000	.63,179	
24	271.494005321AS	20.00000000	CAFL_VUV	1.00000000 1.55928800	56:051	
25	-699.586280479	8.024560977	D_101	1.00000000	56.205 56.555	
26	-153.52828 5 731	10.00000000	CAFL_VUV	.1.55928800	56.558	
27	-560.562638141	0.50000000	-	1.00000000	58 953	
28 .	263.384921460	10.037592987	CAFL_VUV	1.55928800	60.575	
3 <i>9</i> 30	864.791835170	0.500000000		. 1.00000000	60.626	
31	267.241902885 -176.407844045	23.743236926	CAFT_AOA	1.55928800	60.923	
32	80.727620796	0.500000000		1-00000000	60.632	
33	-1567.809778070	23.241259645	CWLT_AOA	1.55928800	51,404	
34	-334.276005123	8.00000000	CAFL_VUV	1.00000000 1.55928800	49.510	
35	363.397520174	0,800000000	ana	1.00000000	49,361 43.590	
36.	91.645466319	21.030369305	CAFL VUV	1.55928800	39.509	
37	196.136325952AS	4.278863057	•	1-00000000	31.382	
· 38	97.703490217	13.616164337	CAFT_AGA	1.55928800	26.772	
40	0.00000000	4.500000000		1.00000000	20.752	
		0.000000000		.1.000000000	14.501	
Asphi	ERISCHE KONSTANTEN		•	•		
	•		• •			
FLAEC	HE NR. 1	•	•			
ж.	-0.9846					
Ċ1	2.126948746-008	•				
		•				
. FLABO	HE NR. 3					
ĸ	-1.7074		•	,	•	
Ĉ1	-9.31272775e-009					
C2	-1.05704321e-015			•		•
C3	4.61520599e-018			٠.		
C4	-5.33078354e-022					
C5	8.27260825e-026			•		
C6	-8.30024327e-030		•			
C7	3.45094228e-034				•	
FLAEC	HENR: 8	•			•	

FLAECHE NR:

į

~0.0456 2.538384550-009 1.117934250-013 2.417500180-017 -1.008951590-020 4.133258235-024 -7:777318816-028 6.500004500-032-

K C1 C3 C4 C5 C6 C7

Table 1- cont.

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C4
C5
C6
C7
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         3.76578322e-018
        -2.50108813e-022
         9.73773615e-027
        -2.139323706-031
2.02907664e-036
FLAECHE NR. 14
         3.5141
Ċl
         1.58869838e-008
C2
         2.693565946-012
С3
         4.930872326-016
C4
C5
        -8.23724826e-020
         4.076420636-023
        -9.01540323e-027
1.00574364e-030
C6
C7
FLAECHE NR. 15
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C1
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C2
C3
C4
C5
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        -6.52020930e-016
       -1.190028726-020
-4.287766786-023
2.944784046-027
C6
FLAECHE NR. 24
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K -25.4029 C1 -2.04498950e-008 C2 -3.73720369e-011 C3 4.01117217e-018 C4 -1.1297926Je-018 C5 1.54644980e-022 C6 -1.63021485e-026

FLAECHE NR. 37

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C1 3.72477051e-007
C2 -1.71322431e-011
C3 -1.20561371e-014
C4 2.13026172e-017
C5 -1.43316568e-020
C6 4.63387907e-024

Table 2

		•		•	•	
j900				·		
FLAE	CHE RADIEN	DICKEN	GLAESER	BRECHEAHL	1/2 FREIER	
				157.63 nm	DURCHNESSER	
٥	0.00000000	38.000000000		1.00000000	73,000	-
1	184.799217499	28.000000000	CAFUV	1.55412431	87.710	•
2	574.400701842A£	14.919168692	. •	1.00000000	87.093	
, з	149.429601044	26.218366158	CAPUV	1,55412431	87.540	
4	258.066811385	29.923376607		1.000000000	84,657	
5	-644.172908775	42.731138000	Cafuv	1.55412431	82.829	
6	4374.612901330	198.843608746	• `	. 1.00000000	79.636	
7 .	-123.151293249	12.000000000	CAFUV	1.55412431	72.144	
8	-486.103678769	36.783449948		1.00000000	85.904	
9	-119.779042846	15.000000000	CAFUV	1.55412431	89.234	
10 .	-177,91007901148			1.00000000		
11	-179.543989755	-1.933693712		1.00000000	106.574	
12	-177.910079011AS		CAFUV	1.55412431	107.751	REFL
13	-119,779042846	-36.763449945			106.959	
14	-486.103678769	-12.000000000	CAFUV	1.00000000	92.783	
15		-198.843608746	CAL U V	1.55412431	92.245	
16	4374.612901330	-42.731138000	CAPUV	1.00000000	82.331	
17 .	-644.172908775	-4.139875858	CVEOA	1.58412431	85.343	
18	-666.363457768	4,139875858		1.00000000	86.261	•
19	-644,172908775	42,731138000	CAFUV	1.00000000	86.682	REFL
20	4374.612901330	584.263905944	CALOV	1.55412431	88-116	
21	-495.625067098AB			1.00000000	102.675	
22	-202.781628516AB			1.00000000	372.773	REFL
23	-204,670915470A6		A	1.00000000	111.384	REFL
. 24	-184.104640410		CAPUV	1.55412431	117.053	•
25		2.231892279		1.00000000	124.249	
26	303.816736042A8		CAFUV	1.55412431	120.675	
27	177,463669677	18.608778547		1.00000000	114.836	•
28	209.468539213AB		CAFUV .	1.55412431	116.751	
29	181.410388840	0,950000041		1-00000000	.110.250	
30	161.869823453A5		CAFUV	1.55412431	115.178	
31	-976.129830622	19.128456290		1.00000000	113,915	
32	-253.85268815FAS		CAFUV	1.55412431	112.517.	
. 32	158,684226172 174.545959776	9.847700125		1.00000000	105.326	
34		29.870669039	CAFUV	1.55412431	110.849	
35	440.082909442AS			1.00000000	110.388	
36	204.334336799	17.595400762	CAFUV	1.55412431	120.406	
37	174.152983444	27.639347321		1.00000000	117.726	
	. 304,178032357	31.789331929	CAPUV	1,55412431	120:777	
38	9745.067330670AB	0.950005077		1.000000000	121.607	
39	1119.767294410	26.451281408	CAFUV	1.55412431	122.352	
40	-711.473281687	-14.030853666	•	1.000,00000	123.495	
41	0-00000000	14.980853656		1.00000000	122,925	
42	300,521153051AS	38.416698821	CAPUV	1.55413431	130.602	٠.
. 43	-3552.584660330	0:92000000		1,00000000	130,493 .	
44	220.251399572	72.477627664	CAFUV	1.55412431	128.726	
45	-394.144465933AS	10.187867467	1	1.00000000	126.321	
46	~305.456017514AS	9.000000000	CAFUV	1.55412431	122.523	
· 47	-401.932510901	0.950000000	•	1.00000000	118.819	•
48	170.697258276AS	29.530325166	CAFUV	1.55412431	93.904	
49	857.300600992	0.950000000		1.00000000	88.838	
50	137.507824910	20.114051970	CAFUV	1.55412431	73.650	
51	219.235388466	5.327505147	•	1.00000000	66.630	
.52	325.168227732AB	49.881856836	CAPUV	1.55412431	62.731	
53	0.000000000	4,053783457	•	1,00000000	30.630	
54	0.000000000	0.000633368		1.00000000	18.250	
ASPHA	ERISCHE KONSTBUTTU		•		20.240	

ASPHAERISCHE KONSTANTEN

FLAECHE NR. 2

X C1 C2 C3 C4 C5

0.0000 2.46982824e-009 2.49363651e-013 -4.61084757e-017 3.33672481e-021 -1.46716649e-025

FLAECHE NR. 10 0.0000 WO 2005/015283 PCT/EP2004/007910

Table 2 - cont.

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Ci.
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2.28110240e-018
-2.79536651e-022
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C4
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C5
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C3
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C4
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Ç5
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7.96718479e-017
ÇZ
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       -3.95924258e-028
C4
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FLAECHE NR. 22
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ĸ
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·C1 ·
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7.57581194e-019
8.21047540e-023
C2
C3
C4
C5
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CI.
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Ç3
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C4
C5
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C4
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C6
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CS
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C1
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C4
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        7.010034578-030
FLAECHE NR. 91
```

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Table 2 - cont.

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 C4
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 C5
C6
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 FLAECHE NR. 34
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 Cl
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 C3
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 FLASCHE NR. 38
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 ĸ
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1.83264934e-017
 C1 ·
 C2 ·
 C3
 C4
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 Cl
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 C4
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 C1
 C3
C4 .
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 Ç5
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 C1
 C2
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 C4
 ĊS
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· C6
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CZ
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-1.541194866-025
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CZ
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-8.91959850e-017
 C3
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        -9.92519663m-024
```

What is claimed is:

- A projection objective including at least two curved mirrors and a plurality of optical elements that all have a common axis of rotational
 symmetry, wherein an axial distance between a next to last curved mirror and a last curved mirror, the order of both mirrors being defined along a light path, is greater than an axial distance between the last curved mirror and a first refracting surface of lenses following the last curved mirror along the light path, the first refracting surface following optically the last curved mirror being associated with a single pass lens,
 wherein a pupil of the objective is free of obscuration.
 - 2. The objective of claim 1, wherein the first refracting surface following the last curved mirror is associated with a negative lens.
- The objective of claim 1, wherein there are four curved mirrors.
- The objective of claim 1, wherein the next to last curved mirror has an opening formed therein to accommodate a lens that is immediately optically
 behind the first refracting surface or the next to last curved mirror is an off axis mirror to permit light rays to travel along the light path.

- 5. The objective of claim 1, wherein a refractive part that is optically behind the last mirror includes more positive lenses than negative lenses.
- The objective of claim 1, including at least two double pass
 lenses optically in front of the next to last mirror.
 - 7. The objective of claim 1, wherein the objective forms an image with a numerical aperture of at least substantially 0.80.
- 10 8. The objective of claim 1, including at least one aspherical reflective surface and at least one aspherical refractive surface.
 - 9. The objective of claim 1, including at least four curved mirrors.
- 15 10. The objective of claim 1, including at least one light-dispersing mirror and at least two light-collecting mirrors.
 - 11. The objective of claim 1, wherein an aperture diaphragm is not followed by a plane mirror.

12. The objective of claim 1, including at least one triple pass lens

located optically in front of the next to last mirror.

- 13. The objective of claim 1, wherein at least three curved mirrors are constructed to have one or more cut out regions which permit light to pass therethrough.
- 5 14. The objective of claim 1, including at least two double pass lenses and one triple pass lens all of which are physically disposed between the two most object forward mirrors.
- 15. The objective of claim 1, including at least two double passlenses physically disposed between the two most object forward mirrors.
 - 16. The objective of claim 1, wherein the first refracting surface is associated with a positive lens.
 - 17. The objective of claim 1, including an aperture stop located in a refractive group of elements optically behind the last mirror.

- 18. The objective of claim 1, wherein the objective forms an image with a numerical aperture of at least substantially 0.95.
- 19. The objective of claim 1, wherein the objective forms an image with a numerical aperture of at least substantially 1.1 in immersion.

- 20. The objective of claim 1, wherein the single pass lens is the only lens element between the next to last mirror and the last mirror as measured along an optical axis.
- 5 21. The objective of claim 1, wherein the objective is free of an intermediate image between the two mirrors.
- 22. A projection objective comprising at least four curved mirrors, including a first curved mirror that is a most optically forward mirror and a second curved mirror that is a second most optically forward mirror, as defined along a light path, and an intermediate lens element disposed physically between the first and second mirrors, the intermediate lens element being a single pass type lens.
- 23. The objective of claim 22, wherein a least image forward
 15 curved mirror and the first curved mirror are disposed back-to-back relative to one another.
 - 24. The objective of claim 22, wherein at least one curved mirror is an off axis mirror relative to an optical axis.

- 25. The objective of claim 22, wherein there at least two lens elements disposed between the two most object forward curved mirrors.
- The objective of claim 25, wherein there are three negative
 lens elements between the two most object forward curved mirrors.
 - 27. The objective of claim 25, wherein at least two lens elements between the two most object forward curved mirrors are double pass lenses.
- 10 28. The objective of claim 22, wherein the second curved mirror has an opening formed therein to accommodate the intermediate lens element.
- 29. The objective of claim 22, further including a plurality of lenses optically behind the intermediate lens element wherein the lenses that are optically behind the first curved mirror include more positive lenses than negative lenses.
 - 30. The objective of claim 22, wherein the objective forms an image with a numerical aperture of at least substantially 0.80.

- 31. The objective of claim 22, including at least one aspherical reflective surface and at least one aspherical refractive surface.
 - 32. The objective of claim 22, including at least one light-
- 5 dispersing mirror and at least two light-collecting mirrors.
 - 33. The objective of claim 22, wherein an aperture diaphragm is not followed by a plane mirror.
- 10 34. The objective of claim 22, including at least one triple pass lens located optically in front of the second curved mirror.
 - 35. The objective of claim 22, including at least two double pass lenses and one triple pass lens all of which are disposed between the two most object forward mirrors.
 - 36. The objective of claim 22, including at least two double pass lenses disposed between the two most object forward mirrors.
- 20 37. The objective of claim 22, including an aperture stop located in a refractive group of elements optically behind the last mirror.

- 38. The objective of claim 22, wherein the objective forms an image with a numerical aperture of at least substantially 0.95.
- The objective of claim 22, wherein a pupil of the objective isfree of obscuration.
 - 40. The objective of claim 22, wherein there is only one intermediate lens element disposed in an optical path between the first and second mirrors.

- 41. The objective of claim 22, wherein the objective is free of an intermediate image between the first and second mirrors.
- 42. A projection exposure apparatus comprising a light source selected from the group of light sources consisting of a DUV and a VUV light source, an illumination system, a reticle handling, positioning and scanning system, a projection objective according to claim 1 and a wafer handling, positioning and scanning system.
- 43. A projection exposure apparatus comprising a light source selected from the group of light sources consisting of a DUV and a VUV light source, an illumination system, a reticle handling, positioning and scanning system, a projection objective according to claim 22 and a wafer handling, positioning and

scanning system.

- 44. A projection objective with four curved mirrors and a refractive lens part, the objective being free of folding mirrors, wherein at least one lens element of the refractive lens part is spatially disposed in front of a next to last curved mirror while being optically behind a last curved mirror, wherein the one lens element is a single pass type lens and the objective has a numerical aperture of at least about 0.80 and is free of an intermediate image between the next to last mirror and last mirror, wherein a maximum diameter of each refractive lens element is less than 1.1 times a diameter of an aperture stop of the objective.
- 45. A projection objective including:

 a catadioptric part with at least two curved mirrors; and

 a refractive part including a single pass lens element that is disposed

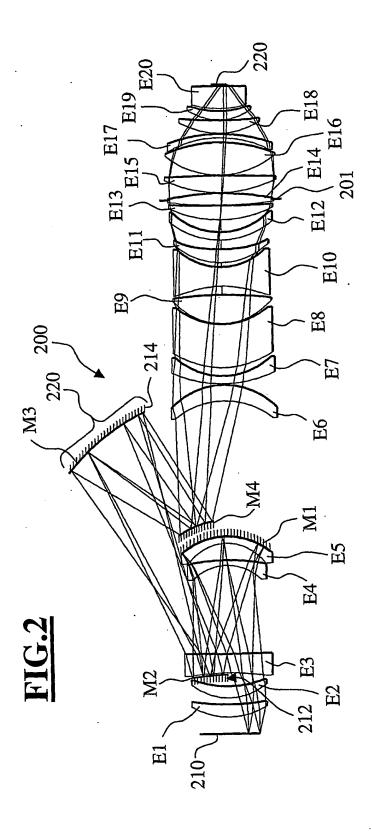
 15 between a next to last curved mirror and a last curved mirror, as defined along a light path, the objective being constructed so that a pupil thereof is free of obscuration, the single pass lens element being the only refractive lens element that is disposed between the next to last curved mirror and the last curved mirror as measured along an optical axis, the refractive part containing an aperture stop with at least one lens

 20 element of the refractive group being in front of the aperture stop.
 - 46. A projection objective including a first catadioptric part comprising at least four curved mirrors and a second refractive part, wherein at least

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one single pass lens element of the refractive part is disposed physically between the last curved mirror and the next to last curved mirror, the mirrors being ordered along a light pass.

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INTERNATIONAL SEARCH REPORT



international Application No

T/EP2004/007910 A. CLASSIFICATION OF SUBJECT MATTER IPC 7 G02B17/08 G03F G03F7/20 According to International Patent Classification (IPC) or to both national classification and IPC B. FIELDS SEARCHED Minimum documentation searched (classification system followed by classification symbols) IPC 7 GO2B GO3F Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched Electronic data base consulted during the international search (name of data base and, where practical, search terms used) EPO-Internal, WPI Data, PAJ C. DOCUMENTS CONSIDERED TO BE RELEVANT Citation of document, with Indication, where appropriate, of the relevant passages Relevant to claim No. X US 2002/012100 A1 (SHAFER DAVID R) 1-46 31 January 2002 (2002-01-31) abstract; figures 2,3 paragraph '0017! - paragraph '0035! US 6 169 627 B1 (SCHUSTER KARL HEINZ) X 1,2,4,5, 2 January 2001 (2001-01-02) 8,11,16, 17,20, 21,42,45 figure 1 column 2, line 56 - column 3, line 63 Further documents are listed in the continuation of box C. Patent family members are listed in annex. Special categories of cited documents: 'T' later document published after the international filing date or priority date and not in conflict with the application but cited to understand the principle or theory underlying the *A* document defining the general state of the art which is not considered to be of particular relevance invention "E" earlier document but published on or after the International "X" document of particular relevance; the cialmed Invention filing date cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone "L" document which may throw doubts on priority claim(s) or which is cited to establish the publication date of another citation or other special reason (as specified) "Y" document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document is combined with one or more other such documents, such combination being obvious to a person skilled in the art. O document referring to an oral disclosure, use, exhibition or other means *P* document published prior to the international filing date but later than the priority date claimed "&" document member of the same patent family Date of the actual completion of the international search Date of mailing of the international search report 27/10/2004 14 October 2004 Name and mailing address of the ISA Authorized officer European Patent Office, P.B. 5818 Patentlaan 2 NL - 2280 HV Rijswijk Tel. (+31-70) 340-2040, Tx. 31 651 epo nl, Fax: (+31-70) 340-3016

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INTERNATIONAL SEARCH REPORT

International Application No T/EP2004/007910

		T/EP2004/007910
	ation) DOCUMENTS CONSIDERED TO BE RELEVANT	
Category °	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
X	DE 100 02 626 A (ZEISS CARL) 26 July 2001 (2001-07-26) figures 1,5,6	1,2,4,5, 7,8,11, 16,17, 20,21, 42,45
	page 5, line 36 - page 7, line 19 page 8, line 36 - page 9, line 2	
X	US 5 592 329 A (SUENAGA YUTAKA ET AL) 7 January 1997 (1997-01-07)	1-3,8,9, 11,13, 22,24, 31,33, 42,43
	figure 5 column 6, line 12 - column 7, line 65	
Х	WO 01/51979 A (ZEISS CARL) 19 July 2001 (2001-07-19) figures 2,3 page 4, line 38 - page 10, line 17	1-46
A	US 2002/024741 A1 (ISHII HIROYUKI ET AL) 28 February 2002 (2002-02-28) cited in the application figures	

INTERNATIONAL SEARCH REPORT

Information on patent family members

international Application No
I/EP2004/007910

`					
Patent document Pu cited in search report		Publication date		Patent family member(s)	Publication date
US 2002012100	A1	31-01-2002	WO EP WO JP TW US	2875301 A 0155767 A2 1247132 A2 0151979 A2 2003536092 T 538256 B 2004027653 A1 2001043391 A1	24-07-2001 02-08-2001 09-10-2002 19-07-2001 02-12-2003 21-06-2003 12-02-2004 22-11-2001
US 6169627	B1	02-01-2001	US DE US EP JP	2004160666 A1 19639586 A1 2003011894 A1 0833180 A2 10104513 A	19-08-2004 02-04-1998 16-01-2003 01-04-1998 24-04-1998
DE 10002626	Α	26-07-2001	DE WO EP JP US US	10002626 A1 0150171 A1 1242843 A1 2003535356 T 2003179356 A1 2003011894 A1	26-07-2001 12-07-2001 25-09-2002 25-11-2003 25-09-2003 16-01-2003
US 5592329	Α	07-01-1997	JP JP	6230287 A 6235863 A	19-08-1994 23-08-1994
WO 0151979	Α .	19-07-2001	AU WO EP WO JP TW US US US	2875301 A 0155767 A2 1247132 A2 0151979 A2 2003536092 T 538256 B 2004027653 A1 2002012100 A1 2001043391 A1 2004160666 A1	24-07-2001 02-08-2001 09-10-2002 19-07-2001 02-12-2003 21-06-2003 12-02-2004 31-01-2002 22-11-2001 19-08-2004
US 2002024741	A1	28-02-2002	JP	2001228401 A	24-08-2001